

# Quad Low-Power Voltage Comparator

PM139

#### 1.0 SCOPE

This specification documents the detailed requirements for Analog Devices space qualified die including die qualification as described for Class K in MIL-PRF-38534, Appendix C, Table C-II except as modified herein.

The manufacturing flow described in the STANDARD DIE PRODUCTS PROGRAM brochure at <a href="http://www.analog.com/marketSolutions/militaryAerospace/pdf/Die Broc.pdf">http://www.analog.com/marketSolutions/militaryAerospace/pdf/Die Broc.pdf</a> is to be considered a part of this specification.

This data sheet specifically details the space grade version of this product. A more detailed operational description and a complete data sheet for commercial product grades can be found at <a href="https://www.analog.com/PM139">www.analog.com/PM139</a>

**2.0 Part Number.** The complete part number(s) of this specification follow:

<u>Part Number</u> <u>Description</u>

PM139-000C Quad Low-Power Voltage Comparator

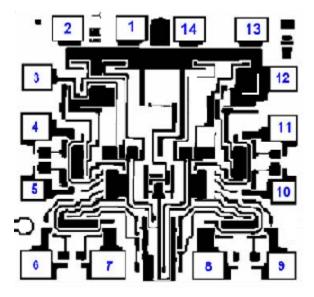
PM139R000C Quad Low-Power Voltage Comparator with Radiation Guarantee

#### 3.0 <u>Die Information</u>

#### 3.1 <u>Die Dimensions</u>

#### 3.2 Die Picture

Die Size	Die Thickness	Bond Pad Metalization
51 mil x 48 mil	19 mil ± 2 mil	Al/Cu



1. OUT 2 8. IN 3-2. OUT 1 9. IN 3+ 3. V+ 10. IN 4-4. IN 1- 11. IN 4+ 5. IN 1+ 12. GND 6. IN 2- 13. OUT 4 7. IN 2+ 14. OUT 3

### PM139

#### Absolute Maximum Ratings 1/ 3.3

Supply Voltage Range	36V dc or ±18V dc
Input Voltage Range	-0.3V dc to 36V dc
Input Current (V <sub>IN</sub> < -0.3V)	. 50mA
Sink Current	
Storage Temperature	
Ambient Operating Temperature Range	
Junction Temperature (T <sub>J</sub> )	150°C

Absolute Maximum Ratings Notes:

1/ Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.

#### **Die Qualification** 4.0

In accordance with class-K version of MIL-PRF-38534, Appendix C, Table C-II, except as modified herein.

- (a) Qual Samples Size and Qual Acceptance Criteria 25/2
- (b) Qual Sample Package DIP
- (c) Pre-screen electrical test over temperature performed post-assembly prior to die qualification.

Table I - Dice Electrical Characteristics							
Parameter	Symbol	Conditions <u>1/</u>	Limit Min	Limit Max	Units		
Input Offset Voltage	V <sub>IO</sub>			±2	mV		
Input Offset Current	<b>I</b> 10	I - I with output in the linear range		25	nA		
Input Bias Current	<b>I</b> IB	I - I with output in the linear range		100	nA		
Output Sink Current	<b>I</b> SINK	$V_{IN-} \ge 1V, V_{IN+} = 0V,$ $V_{O} \le 1.5V$	6		mA		
Saturation Voltage	V SAT	$V_{IN-} \ge 1V, V_{IN+} = 0V,$ $I_{SINK} \le 4mA$		400	mV		
Output Leakage Current	<b> </b> LEAK	$V_{IN-} = 0V, V_{IN+} \ge 1V dc V_{o} = 30V$		0.5	μΑ		
Supply Current	l cc	R <sub>L</sub> = ∞, V+ = 30V		3	mA		
Input Voltage Common Mode Rejection Ratio	CMRR	V+ = 15V, $V_{CM}$ = 0V to 13.5V, $R_{L} \ge 15kΩ$	60.5		dB		

Table I Notes:

 $\underline{1/}$  V+ = +5V, V- = 0V, V<sub>O</sub> = 1.4V, V<sub>IN</sub> = 0V, and T<sub>A</sub> = 25°C, unless otherwise specified.

Table II - Electrical Characteristics for Qual Samples									
Parameter	Symbol	Conditions 1/		Sub- groups	Limit Min	Limit Max	Units		
				1		±2			
Input Offset Voltage	V <sub>IO</sub>			2, 3		±4	mV		
			<u>2</u> /	1		3			
		I <sub>IN+</sub> - I <sub>IN-</sub> with out	put in the linear	1		±25			
Input Offset Current	lio	rar	nge	2, 3		±100			
			<u>2</u> /	1		±25	nA		
		I <sub>IN+</sub> - I <sub>IN-</sub> with out	put in the linear	1		±100	IIA		
Input Bias Current	I <sub>IB</sub>	range		2, 3		±300	1		
			<u>2</u> /	1		±100			
Output Sink Current	Isink		V <sub>IN+</sub> = 0V, .5V <u>3</u> /	1	6		mA		
		$V_{IN} \geq 1V, V_{IN+} = 0V, \\ I_{SINK} \leq 4mA$		1		400			
Saturation Voltage	$V_{SAT}$			2, 3	3 700	700	mV		
			<u>2</u> /	1		400			
		$V_{IN-} = 0V,V$	<sub>IN+</sub> ≥ 1V dc,	1		0.5			
Output Leakage Current	I <sub>LEAK</sub>	V <sub>0</sub> =	30V	2, 3		1	μΑ		
5511, 511,			<u>2</u> /			0.5			
Supply Current	lcc	R <sub>L</sub> = ∞, \	/+ = 30V	1, 2, 3		3	mA		
зирріу сипепі	ICC		<u>2</u> /	1		2	IIIA		
Input Voltage Common Mode	CMRR	V+ = 15V, R <sub>L</sub> ≥	$V_{CM} = 0V \text{ to } 13.5V$	1	60.5		dB		
Rejection Ratio	CIVINK	15kΩ $\underline{3}$ / $V_{CM} = 0V \text{ to } 13V$		2, 3	00.5		UD		

# Table II Notes: 1/2/3/

V+ = +5V, V- = 0V, V\_O = 1.4V, and V\_IN = 0V, unless otherwise specified. Post 100Krad limit Not tested post irradiation.

# Table III - Life Test Endpoint and Delta Parameter (Product is tested in accordance with Table II with the following exceptions)

Parameter	Symbol	Sub- groups	Post Bur	n In Limit		ife Test nit	Life Test Delta		Units
			Min	Max	Min	Max			
Input Offset Voltage	V <sub>IO</sub>	1		±3.5		±5	±1.5	mV	
input Onset voltage		2, 3				±7			
Input Bias Current	<b>I</b> IB	1		±115		±130	±15	nA	
пірисыаз сипенс		2, 3				±330			
Input Offset Current	<b>I</b> 10	1		±30		±35		nA	
		2, 3				±100			

### 5.0 <u>Life Test/Burn-In Information</u>

- 5.1 HTRB is not applicable for this drawing.
- 5.2 Burn-in is per MIL-STD-883 Method 1015 test condition B or C.
- 5.3 Steady state life test is per MIL-STD-883 Method 1005.

## PM139

Rev	Description of Change	Date
Α	Initiate	07-Feb-02
В	Add CMVR for temperature different than subgroup 1. (0V to 13V)	10-Apr-02
С	Add 100Krad irradiation limits to table II. Update web address.	6-Jan-03
D	Correct die picture. Changed from LCC die picture to DIP die picture.	17-Feb-05
E	Update the 1.0 Scope Description	13-Jul-07
F	Update header/footer and add to 1.0 scope description.	Feb. 13,2008
G	Added Junction Temperature (T <sub>J</sub> ) 150°C to 3.3- Absolute Maximum Ratings	March 31, 2008
Н	Updated Section 4.0c note to indicate pre-screen temp testing being performed.	6-JUN-2009
I	Updated fonts and font sizes to ADI standards and updated Die picture	1-OCT-2011